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March 2016

FDB0190N807L

N-Channel PowerTrench[®] MOSFET 80 V, 270 A, 1.7 m Ω

Features

- Max $r_{DS(on)}$ = 1.7 m Ω at V_{GS} = 10 V, I_D = 34 A
- Max $r_{DS(on)}$ = 2 m Ω at V_{GS} = 8 V, I_D = 31 A
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low R_{DS(on)}
- High Power and Current Handling Capability
- RoHS Compliant

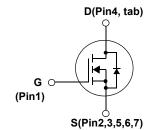


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advance PowerTrench® process that has been especially tailored to minimize the on-state resistance while maintaining superior ruggedness and switching performance for industrial applications.

Applications

- Industrial Motor Drive
- Industrial Power Supply
- Industrial Automation
- Battery Operated tools
- Battery Protection
- Solar Inverters
- UPS and Energy Inverters
- Energy Storage
- Load Switch





1. Gate

2. Source/Kelvin Sense 3. Source/Kelvin Sense

4. Drain

4. Drain

5. Source

6. Source 7. Source

D2-PAK (TO263)

MOSFET Maximum Ratings T_C = 25 °C unless otherwise noted.

Symbol	Parame		Ratings	Units	
V_{DS}	Drain to Source Voltage			80	V
V_{GS}	Gate to Source Voltage			±20	V
	Drain Current -Continuous	T _C = 25°C	(Note 5)	270	
I_D	-Continuous	T _C = 100°C	(Note 5)	190	Α
	-Pulsed		(Note 4)	1440	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	777	mJ
В	Power Dissipation	T _C = 25°C		250	w
P_{D}	Power Dissipation	T _A = 25°C	(Note 1a)	3.8	VV
T _J , T _{STG}	Operating and Storage Junction Temperat	ture Range		-55 to +175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	0.6	°CAM
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	40	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB0190N807L	FDB0190N807L	D2-PAK-7L	330 mm	24 mm	800 units

Electrical Characteristics T_J = 25 °C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Chara	cteristics					
BV_{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	80			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		34		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 64 V, V _{GS} = 0 V			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	2.9	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		-13		mV/°C
		V _{GS} = 10 V, I _D = 34 A		1.3	1.7	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 8 \text{ V}, I_D = 31 \text{ A}$		1.5	2	mΩ
		V_{GS} = 10 V, I_D = 34 A, T_J = 150°C		2.3	4.3	
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 34 A		133		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V - 40 V V - 0 V	13650	19110	pF
C _{oss}	Output Capacitance	V _{DS} = 40 V, V _{GS} = 0 V, f = 1 MHz	1990	2790	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 101112	235	330	pF
R_g	Gate Resistance		2.9		Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		60	96	ns
t _r	Rise Time	V _{DD} = 40 V, I _D = 34 A,	78	125	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω	98	157	ns
t _f	Fall Time		50	80	ns
Qg	Total Gate Charge	V 40.V I 04.A	178	249	nC
Q _{gs}	Gate to Source Gate Charge	$V_{DD} = 40 \text{ V}, I_{D} = 34 \text{ A},$ $V_{GS} = 10 \text{ V}$	60		nC
Q_{gd}	Gate to Drain "Miller" Charge	VGS - 10 V	32		nC

Drain-Source Diode Characteristics

Is	Maximum Continuous Drain to Source Diode Forward Current				270	Α
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current				1440	Α
V_{SD}	Source to Drain Diode Forward Voltage	je V _{GS} = 0 V, I _S = 34 A (Note 2)		0.8	1.2	V
t _{rr}	Reverse Recovery Time	I _F = 34 A, di/dt = 100 A/μs		89	142	ns
Q _{rr}	Reverse Recovery Charge			103	165	nC

^{1.} R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.

a) 40 °C/W when mounted on a 1 in 2 pad of 2 oz copper. b) 62.5 °C/W when mounted on a minimum pad of 2 oz copper.

^{2.} Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0 %.

^{3.} E_{AS} of 777 mJ is based on starting T_J = 25 °C, L = 0.3 mH, I_{AS} = 72 A, V_{DD} = 72 V, V_{GS} = 10 V. 100% test at L = 0.1 mH, I_{AS} = 104 A.

^{4.} Pulsed Id please refer to Figure "Forward Bias Safe Operating Area" for more details.

^{5.} Computed continuous current limited to Max Junction Temperature only, actual continuous current will be limited by thermal & electro-mechanical application board design.

Typical Characteristics T_J = 25 °C unless otherwise noted.

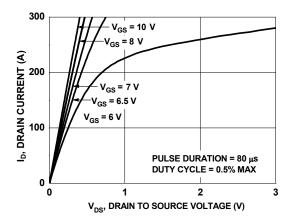


Figure 1. On Region Characteristics

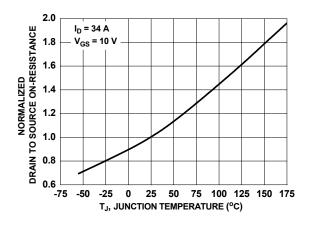


Figure 3. Normalized On Resistance vs. Junction Temperature

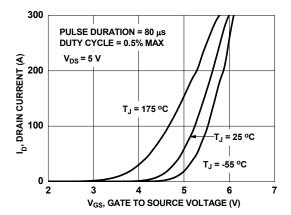


Figure 5. Transfer Characteristics

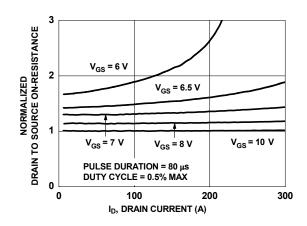


Figure 2. Normalized On-Resistance vs. Drain Current and Gate Voltage

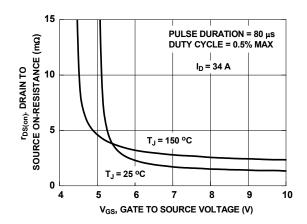


Figure 4. On-Resistance vs. Gate to Source Voltage

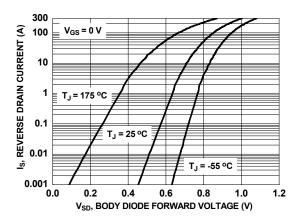


Figure 6. Source to Drain Diode Forward Voltage vs. Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted.

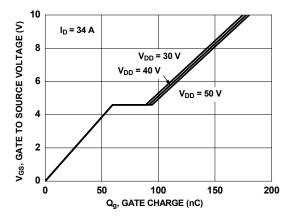


Figure 7. Gate Charge Characteristics

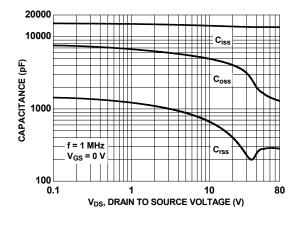


Figure 8. Capacitance vs. Drain to Source Voltage

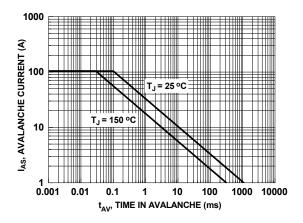


Figure 9. Unclamped Inductive Switching Capability

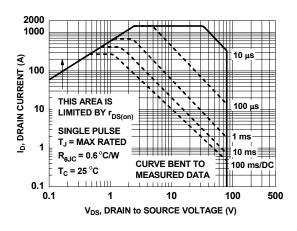


Figure 10. Forward Bias Safe Operating Area

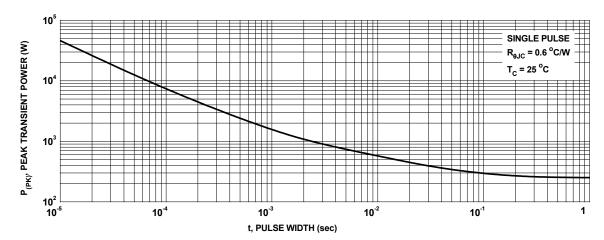


Figure 11. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25$ °C unless otherwise noted.

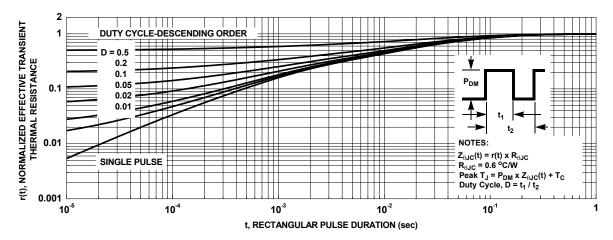
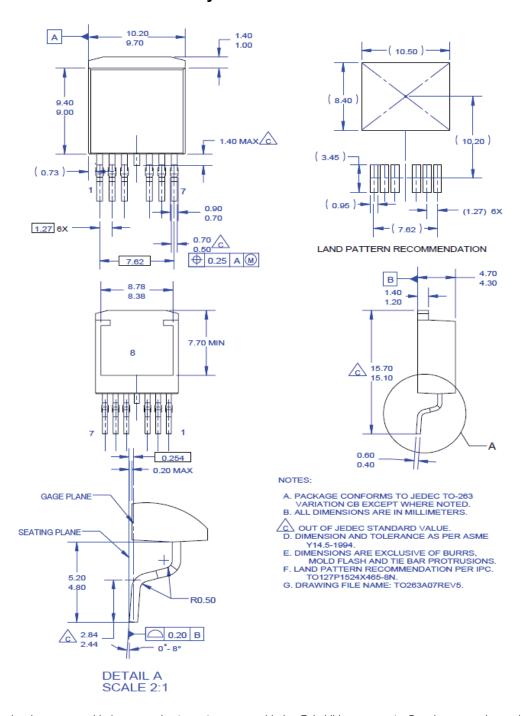


Figure 12. Junction-to-Case Transient Thermal Response Curve

Dimensional Outline and Pad Layout



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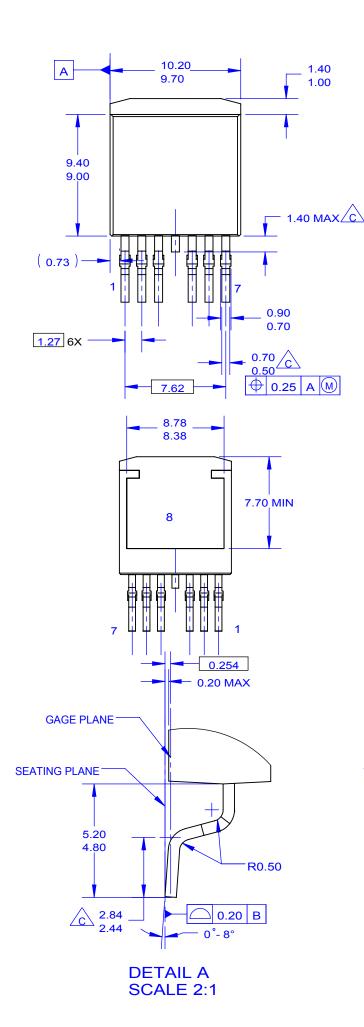
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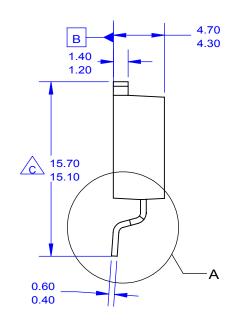
Datasheet Identification Product Status		Definition
Advance Information Formative / In Design		Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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Rev. 177



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